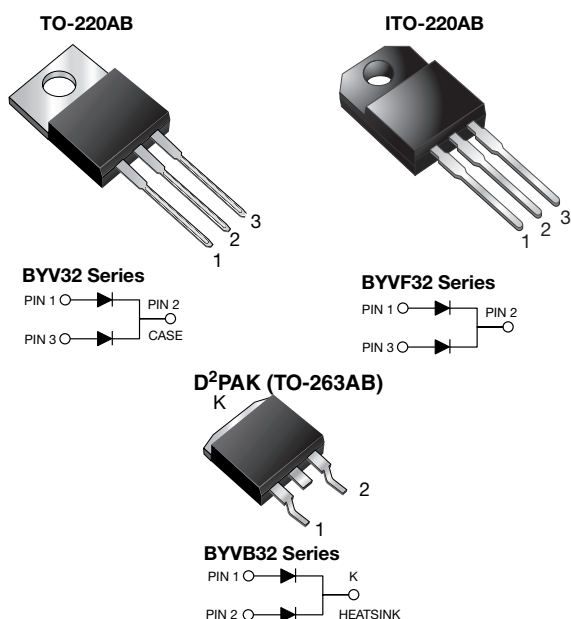


Dual Common-Cathode Ultrafast Rectifier



LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | |
|-------------------------|---------------------------------------|
| $I_{F(AV)}$ | 18 A |
| V_{RRM} | 50 V to 200 V |
| I_{FSM} | 150 A |
| t_{rr} | 25 ns |
| V_F | 0.85 V |
| T_J max. | 150 °C |
| Package | TO-220AB, ITO-220AB, D²PAK (TO-263AB) |
| Circuit configuration | Common cathode |

FEATURES

- Power pack
- Glass passivated pellet chip junction
- Ultrafast recovery time
- Low switching losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
 - Automotive ordering code:
 - base P/NHE3 (for ITO-220AB)
 - base P/NHM3 (for D²PAK (TO-263AB package))
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE
Available

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified ("_X" denotes revision code e.g. A, B,...)

Base P/N-M3 - RoHS-compliant, halogen-free, commercial grade

Base P/NHM3 - RoHS-compliant, halogen-free, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 and M3 suffix meets JESD 201 class 1A whisker test, HE3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

**MAXIMUM RATINGS** ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

| PARAMETER | SYMBOL | BYV32-50 BYVF32-50 | BYV32-100 BYVF32-100 | BYV32-150 BYVF32-150 | BYV32-200 BYVF32-200 BYVB32-200 | UNIT |
|--|----------------|-----------------------|-------------------------|-------------------------|---------------------------------------|--------------------|
| Maximum repetitive peak reverse voltage | V_{RRM} | 50 | 100 | 150 | 200 | V |
| Maximum RMS voltage | V_{RMS} | 35 | 70 | 105 | 140 | V |
| Maximum DC blocking voltage | V_{DC} | 50 | 100 | 150 | 200 | V |
| Maximum average forward rectified current at $T_C = 125\text{ }^{\circ}\text{C}$ | $I_{F(AV)}$ | 18 | | | | A |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | I_{FSM} | 150 | | | | A |
| Operating storage and temperature range | T_J, T_{STG} | -65 to +150 | | | | $^{\circ}\text{C}$ |
| Isolation voltage (ITO-220AB only) from terminal to heatsink $t = 1\text{ min}$ | V_{AC} | 1500 | | | | V |

ELECTRICAL CHARACTERISTICS ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

| PARAMETER | TEST CONDITIONS | | SYMBOL | BYV32-50 BYVF32-50 | BYV32-100 BYVF32-100 | BYV32-150 BYVF32-150 | BYV32-200 BYVF32-200 BYVB32-200 | UNIT |
|---|--|-------------------------|-------------------------------|-----------------------|-------------------------|-------------------------|---------------------------------------|------|
| Maximum instantaneous forward voltage per diode | I _F = 20 A | T _J = 25 °C | V _F ⁽¹⁾ | 1.15 | | | | V |
| | I _F = 5.0 A | T _J = 100 °C | | 0.85 | | | | |
| Maximum DC reverse current per diode at rated DC blocking voltage | | T _J = 25 °C | I _R | 10 | | | | μA |
| | | T _J = 100 °C | | 600 | | | | |
| Maximum reverse recovery time per diode | I _F = 1 A, V _R = 30 V dI/dt = 100 A/μs, I _{rr} = 10 % I _{RM} | | t _{rr} | 25 | | | | ns |
| Typical junction capacitance per diode | 4.0 V, 1 MHz | | C _J | 45 | | | | pF |

Note(1) Pulse test: 300 μs pulse width, 1 % duty cycle**THERMAL CHARACTERISTICS** ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

| PARAMETER | SYMBOL | BYV | BYVF | BYVB | UNIT |
|--|-----------------|-----|------|------|-----------------------------|
| Typical thermal resistance from junction to case per diode | $R_{\theta JC}$ | 1.6 | 5.0 | 1.6 | $^{\circ}\text{C}/\text{W}$ |

ORDERING INFORMATION (Example)

| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
|-------------------------------|----------------------------------|-----------------|--------------|---------------|---------------|
| TO-220AB | BYV32-200-E3/45 | 1.85 | 45 | 50/tube | Tube |
| ITO-220AB | BYVF32-200-E3/45 | 1.97 | 45 | 50/tube | Tube |
| D ² PAK (TO-263AB) | BYVB32-200-M3/I | 1.35 | I | 800/reel | Tape and reel |
| ITO-220AB | BYVF32-200HE3_A/P ⁽¹⁾ | 1.97 | P | 50/tube | Tube |
| D ² PAK (TO-263AB) | BYVB32-200HM3/I ⁽¹⁾ | 1.35 | I | 800/reel | Tape and reel |

Note(1) AEC-Q101 qualified, available in ITO-220AB and D²PAK (TO-263AB) package



RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

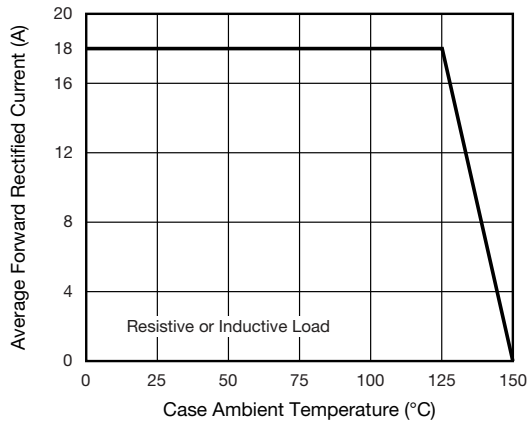


Fig. 1 - Forward Current Derating Curve

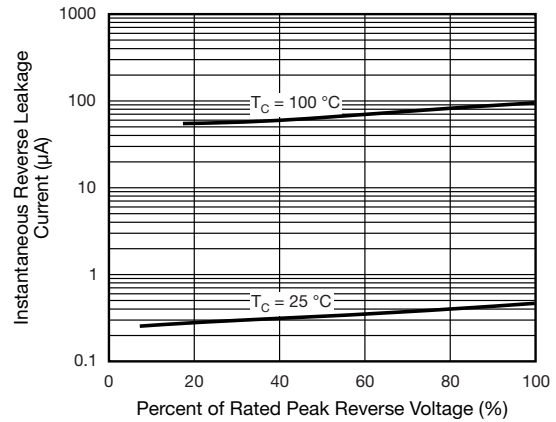


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

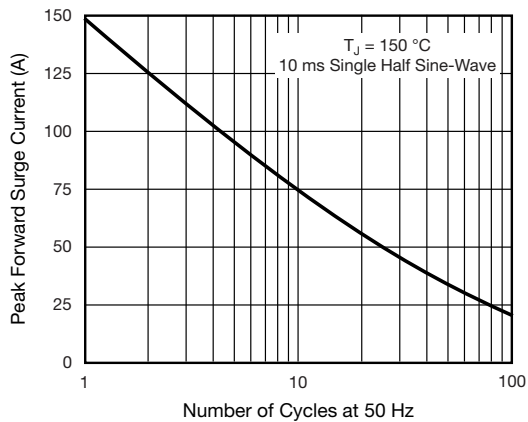


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

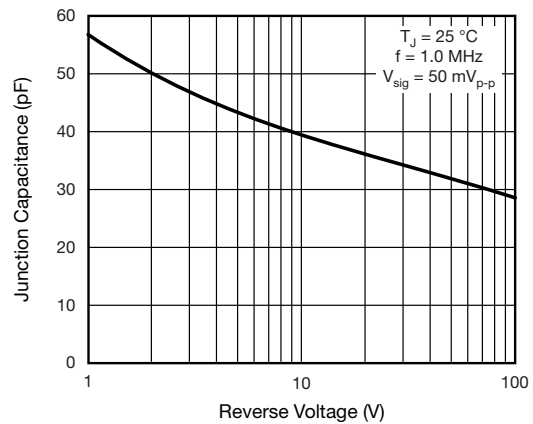


Fig. 5 - Typical Junction Capacitance Per Diode

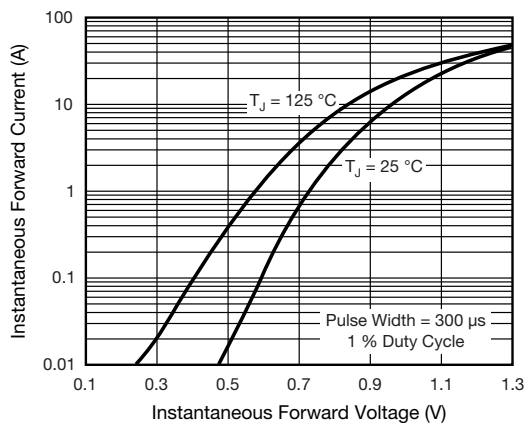
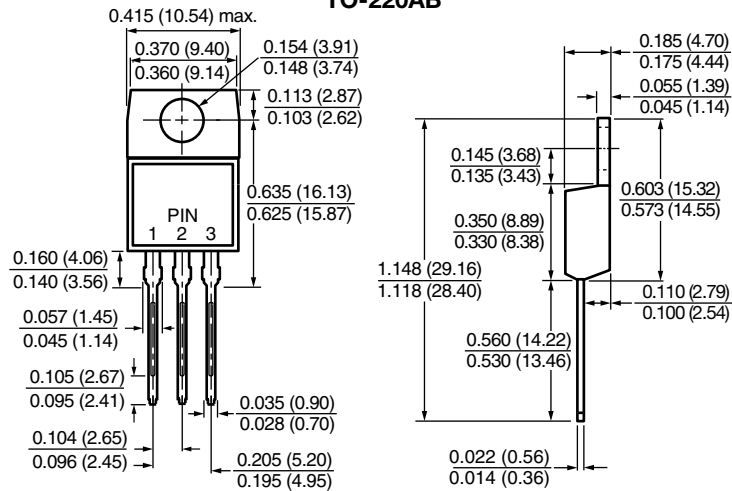


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

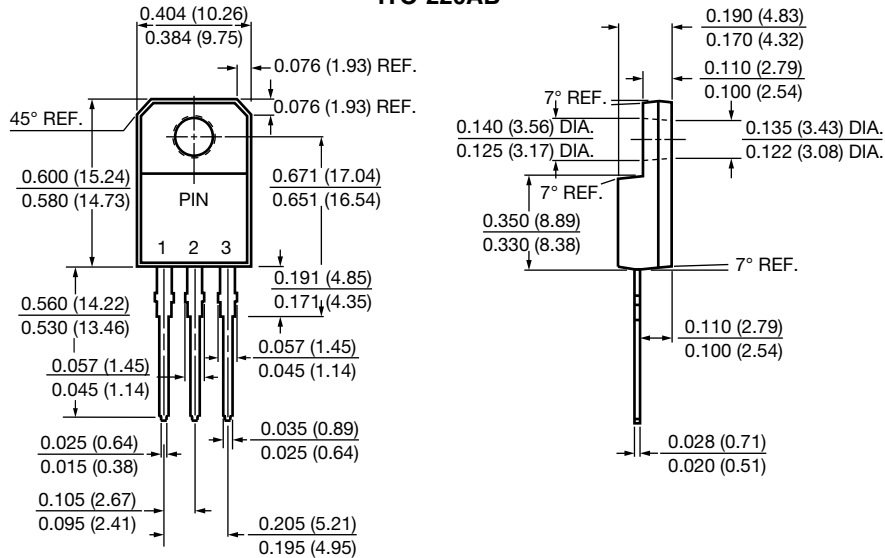


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

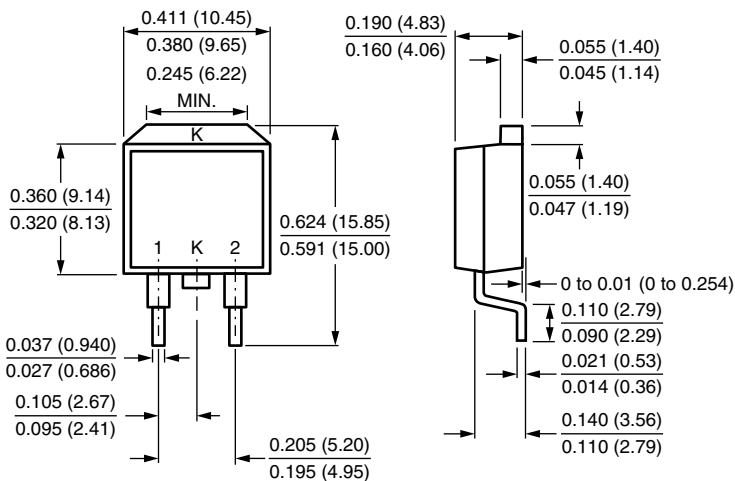
TO-220AB



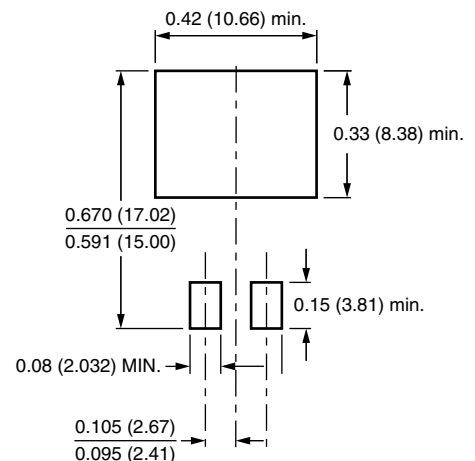
ITO-220AB



D²PAK (TO-263AB)



Mounting Pad Layout





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